

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S109	25	(michael near2 tischler or thomas near2 kuech or robert near2 vaudo). in. and remov\$5 near10 substrate and (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 19:51
S108	35	(michael near2 tischler or thomas near2 kuech or robert near2 vaudo). in. and remov\$5 near10 substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 19:51
S111	3	("4622083" "4727047" "4931132"). PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 19:53
S114	44	lateral near10 (Gan or gallium near2 nitride) and @py<"2000"	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 19:54
S113	2	lateral near4 grow\$6 near10 (Gan or gallium near2 nitride) and @py<"2000"	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 19:54
S112	393	lateral near4 grow\$6 near10 (Gan or gallium near2 nitride)	US-PGPUB; USPAT; USOCR	OR	ON	2005/06/23 19:54
S116	3074	etch near2 stop near10 thick\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 19:57
S115	4	("4931132" "4622083").pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 19:57
S110	24	(michael near2 tischler or thomas near2 kuech or robert near2 vaudo). in. and remov\$5 near10 substrate and (gan or gallium near2 nitride) near10 single near2 crystal\$7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 19:57
S117	2	etch near2 stop near10 thick\$5 near15 (Gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 20:06
S118	54	etch near2 stop near10 thick\$5 and (Gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 20:09

S11 9	43	etch near2 stop near10 (boron near2 nitride or bn)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 20:11
S12 0	2	etch near2 stop near10 (boron near2 nitride or bn) near15 thick\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 20:13
S12 2	43	etch near2 stop near10 (boron near2 nitride or bn)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 20:14
S12 1	8	stop near10 (boron near2 nitride or bn) near15 thick\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/23 20:14
S12 3	8	etch near2 stop near10 (boron near2 nitride or bn) and etch near2 stop near10 thick\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:35
L3	422	remov\$5 near5 (substrate or sapphire) and single near2 crystal\$6 near5 (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:46
L2	459	remov\$5 near5 (substrate or sapphire) and single near2 crystal\$6 near10 (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:46
L1	519	remov\$5 near15 (substrate or sapphire) and single near2 crystal\$6 near10 (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:46
L4	46	remov\$5 near5 (substrate or sapphire) and single near2 crystal\$6 near5 (gan or gallium near2 nitride) and @py<"2000"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:49
L5	3	single near2 crystal\$6 near5 (gan or gallium near2 nitride) and @py<"2000" and 117/97.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:50

L8	370	(gan or gallium near2 nitride) and @py<"2000" and (substrate or wafer) near5 remov\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:51
L7	458	(gan or gallium near2 nitride) and @py<"2000" and (substrate or wafer) near10 remov\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:51
L6	7	(gan or gallium near2 nitride) and @py<"2000" and 117/97.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:51
L11	105	(gan or gallium near2 nitride) near10 (crystal\$6 or crystallin\$5) and @py<"2000" and (substrate or wafer) near5 remov\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:52
L12	6	(gan or gallium near2 nitride) near10 (crystal\$6 or crystallin\$5) and @py<"2000" and (substrate or wafer) near5 sacrific\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/06/24 12:53